## NSN 5961-01-375-9256

**Fiig:** A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-375-9256 **Inclosure Material:** Glass **Overall Length:** 0.141 inches **Terminal Length:** 1.000 inches **Overall Diameter:** 0.062 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-35 **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Cubic Measure:** 0.001 cubic inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 1.0 forward voltage, dc and 125.0 reverse voltage, instantaneous **Current Rating Per Characteristic:** 1.00 nanoamperes collector current, dc peak and 200.00 milliamperes all primaries preset **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead **Specification Data:** 28480-1901-1347 manufacturers specification control Shelf Life: N/a **Unit Of Measure: Demilitarization:** No